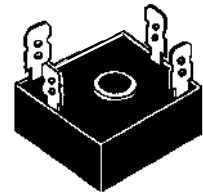
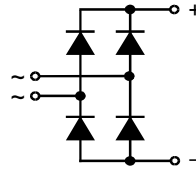


# Single Phase Rectifier Bridge

$$I_{dAVM} = 21 \text{ A}$$

$$V_{RRM} = 1200-1800 \text{ V}$$

$V_{RSM}$ V	$V_{RRM}$ V	Type
1200	1200	VBO 22-12NO8
1400	1400	VBO 22-14NO8
1600	1600	VBO 22-16NO8
1800	1800	VBO 22-18NO8



Symbol	Test Conditions	Maximum Ratings	
$I_{dAV}$	$T_C = 85^\circ\text{C}$ , module	17 A	
$I_{dAVM}$	$T_C = 63^\circ\text{C}$ , module	21 A	
$I_{FSM}$	$T_{VJ} = 45^\circ\text{C}$ ; $V_R = 0$	$t = 10 \text{ ms}$ (50 Hz), sine	380 A
		$t = 8.3 \text{ ms}$ (60 Hz), sine	440 A
$I^2t$	$T_{VJ} = T_{VJM}$ $V_R = 0$	$t = 10 \text{ ms}$ (50 Hz), sine	360 A
		$t = 8.3 \text{ ms}$ (60 Hz), sine	400 A
$I^2t$	$T_{VJ} = 45^\circ\text{C}$ $V_R = 0$	$t = 10 \text{ ms}$ (50 Hz), sine	725 A <sup>2</sup> s
		$t = 8.3 \text{ ms}$ (60 Hz), sine	800 A <sup>2</sup> s
$T_{VJ}$	$T_{VJ} = T_{VJM}$ $V_R = 0$	$t = 10 \text{ ms}$ (50 Hz), sine	650 A <sup>2</sup> s
		$t = 8.3 \text{ ms}$ (60 Hz), sine	650 A <sup>2</sup> s
$T_{VJ}$		-40...+150 °C	
$T_{VJM}$		150 °C	
$T_{stg}$		-40...+150 °C	
$V_{ISOL}$	50/60 Hz, RMS $I_{ISOL} \leq 1 \text{ mA}$	$t = 1 \text{ min}$	2500 V~
		$t = 1 \text{ s}$	3000 V~
$M_d$	Mounting torque (M5) (10-32 UNF)		$2 \pm 10 \%$ Nm
			$18 \pm 10 \%$ lb.in.
Weight	typ.	22 g	

## Features

- Package with ¼" fast-on terminals
- Isolation voltage 3000 V~
- Planar passivated chips
- Blocking voltage up to 1800 V
- Low forward voltage drop
- UL registered E 72873

## Applications

- Supplies for DC power equipment
- Input rectifiers for PWM inverter
- Battery DC power supplies
- Field supply for DC motors

## Advantages

- Easy to mount with one screw
- Space and weight savings
- Improved temperature and power cycling

Symbol	Test Conditions	Characteristic Values	
$I_R$	$T_{VJ} = 25^\circ\text{C}$ ; $T_{VJ} = T_{VJM}$	$V_R = V_{RRM}$ $V_R = V_{RRM}$	$\leq 0.3 \text{ mA}$
			$\leq 5.0 \text{ mA}$
$V_F$	$I_F = 150 \text{ A}$ ; $T_{VJ} = 25^\circ\text{C}$		$\leq 2.2 \text{ V}$
$V_{T0}$	For power-loss calculations only		0.85 V
$r_T$			12 mΩ
$R_{thJC}$	per diode; DC current per module		8.2 K/W
			2.05 K/W
$R_{thJK}$	per diode; DC current per module		9.4 K/W
			2.35 K/W
$d_s$	Creeping distance on surface		12.7 mm
$d_A$	Creepage distance in air		9.4 mm
$a$	Max. allowable acceleration		50 m/s <sup>2</sup>

Data according to IEC 60747 and refer to a single diode unless otherwise stated.  
IXYS reserves the right to change limits, test conditions and dimensions.

## Dimensions in mm (1 mm = 0.0394")

